

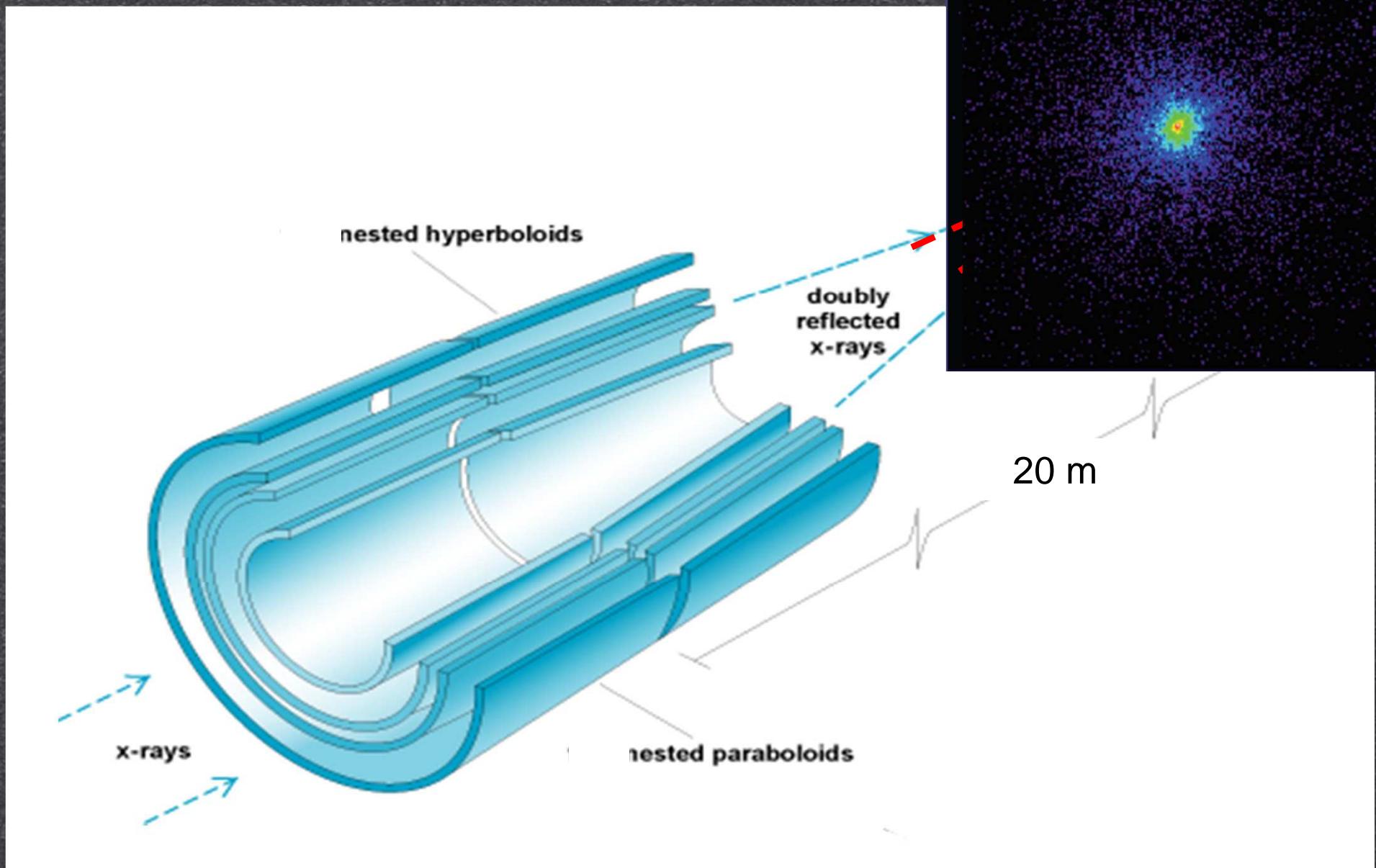


# X-ray scattering of periodic and graded multilayer: comparison of experiments to simulation from surface microroughness characterization

X-Ray Optic Group, INAF OAB



# X-rays telescope



# XMM-Newton



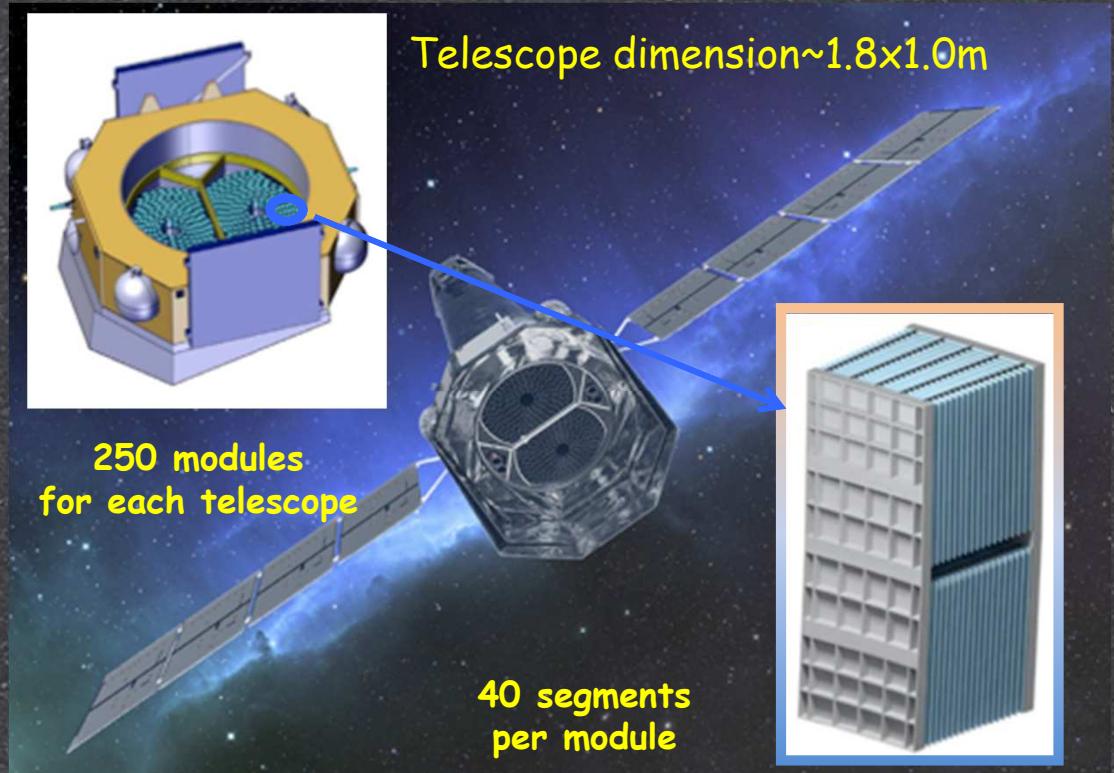
58 mirrors/telescope  
Ø outer mirror = 70 cm

Electroformed Nickel  
Au coating

HEW = 15 arcsec  
Maximum energy = 15 keV

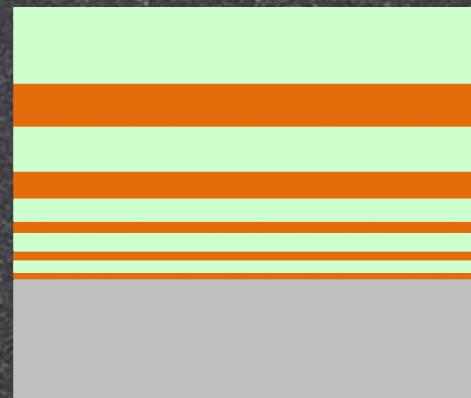
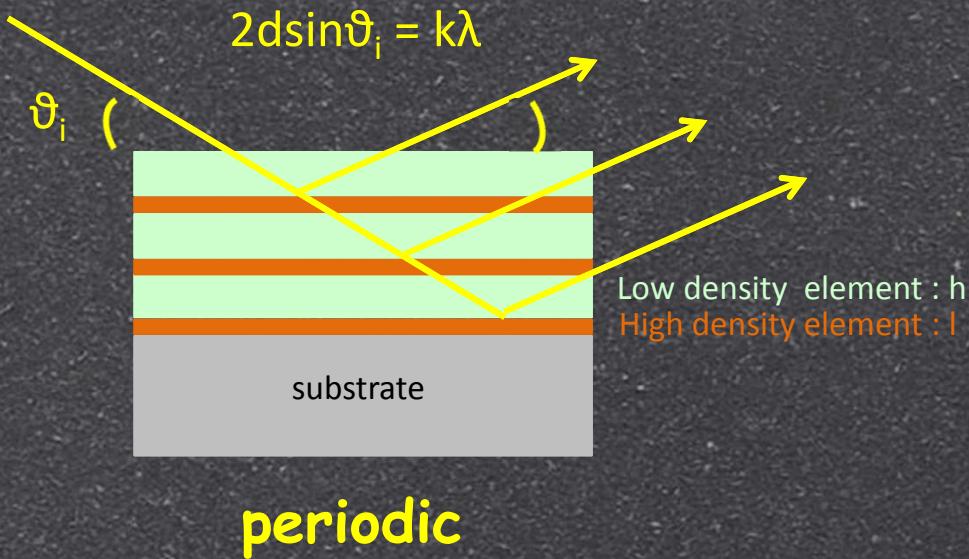
# ATHENA

(Advanced Telescope for High ENergy Astrophysics)  
formerly IXO (X-Ray Observatory)



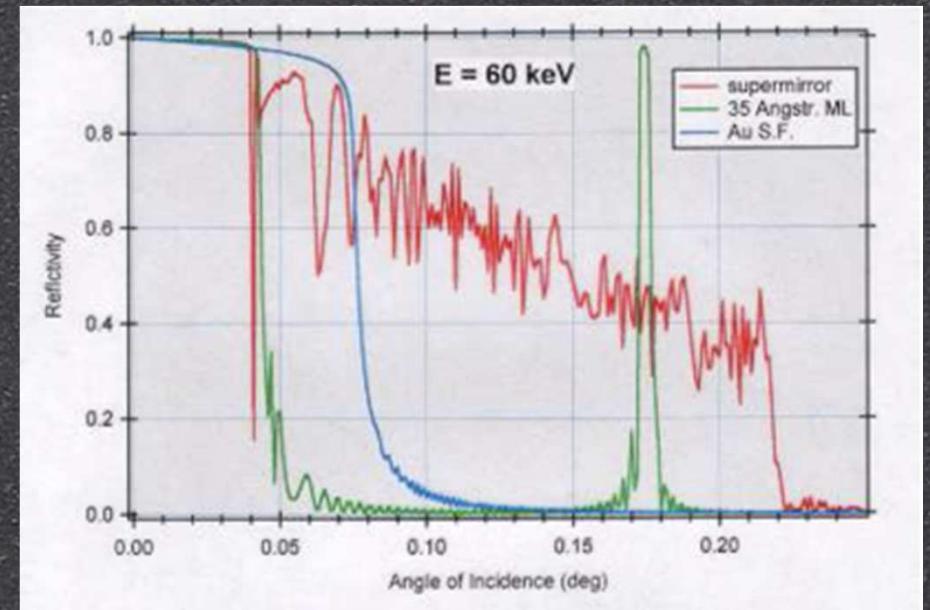
Coated with ...

# ... graded multilayers to reflect hard X-rays



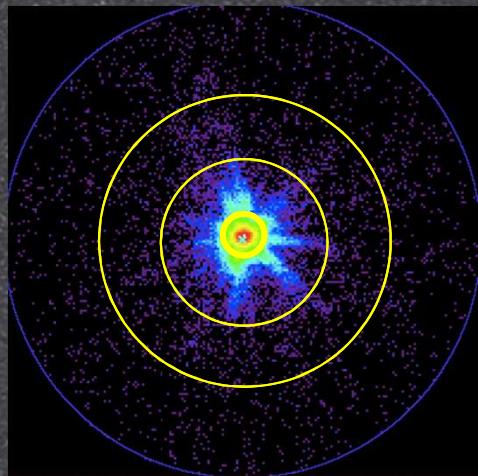
$$d(k) = \frac{a}{(b+k)^c}$$

$$\Gamma = \frac{d_h}{d_h + d_l}$$



# Requirement for Athena : HEW < 10 arcsec (0.1-7 keV) , goal 5 arcsec

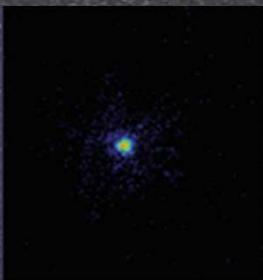
HEW : Half Energy Width



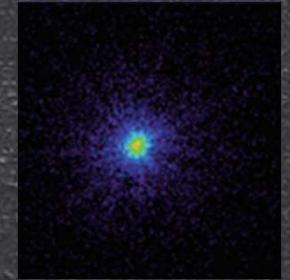
5 arcsec ~ 24 μrad !!



10.000 glasses shaped  
with replication technique !!



We have to control the scattering  
because it affects the HEW



$$HEW(\lambda) = f(H_{figure-errors}) + f(H_{XRS}(\lambda))$$

$$H_{XRS}(\lambda) = f(roughness)$$

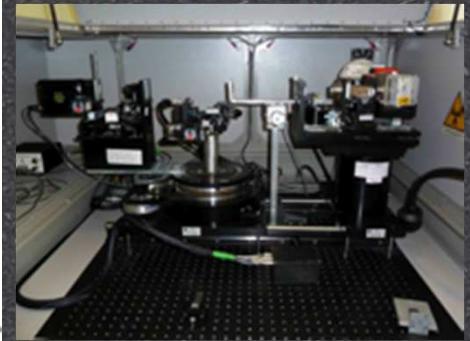
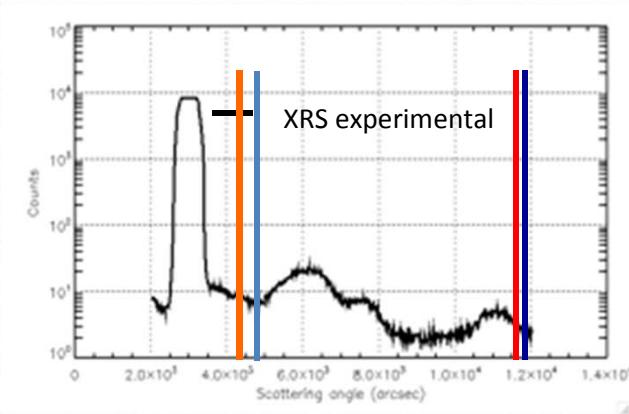
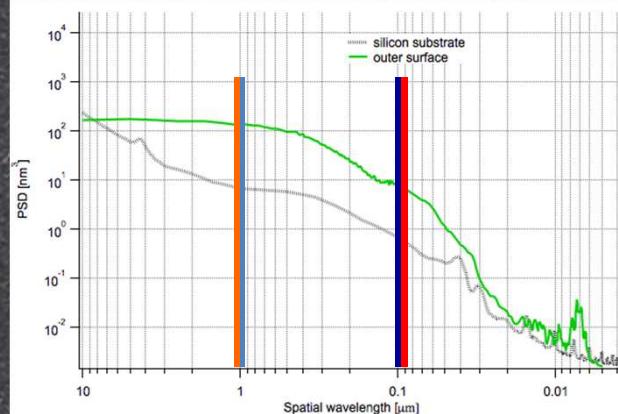
We measure roughness with AFM and XRS with diffractometer. WHY

## AFM ?

Where do AFM spatial frequencies do scatter ?



AFM



X-ray diffractometer

For E=8.045 keV (1.54 Å)

$$l = \frac{1}{f} = \frac{\lambda}{|\cos \vartheta_s - \cos \vartheta_i|}$$

| $\vartheta_i$<br>[arcsec] | $l$<br>[μm] | $\vartheta_s$<br>[arcsec] |
|---------------------------|-------------|---------------------------|
| 3000                      | 10          | 3211                      |
| "                         | 1           | 4701                      |
| "                         | 0.1         | 11835                     |
| "                         | 0.01        | 36368                     |
| 2200                      | 10          | 2480                      |
| "                         | 1           | 4236                      |
| "                         | 0.1         | 11657                     |
| "                         | 0.01        | 36310                     |

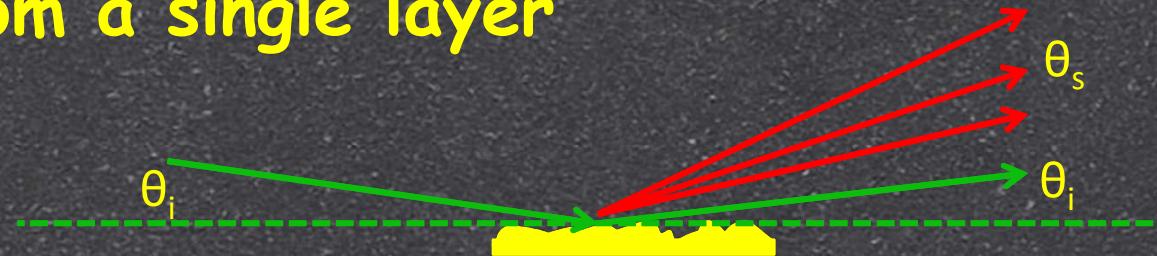


# How we compute the XRS from roughness data ?

- X-ray scattering is computed within the first order perturbation theory for multilayers
- The roughness evolution of layers other then the substrate and the outer one are computed with the Stearns model



## ➤ X-ray scattering from a single layer



First order perturbation theory

- ✧ Smooth ( $2\sigma \sin \theta_i \ll \lambda$ )
- ✧ and isotropic surface



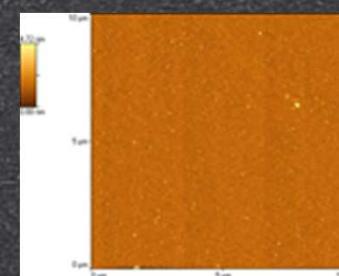
$$\frac{1}{I_0} \frac{dI_s}{d\theta_s} = \frac{16\pi^2}{\lambda^3} Q_{is} \sin^2 \theta_s \sin \theta_i P(f)$$



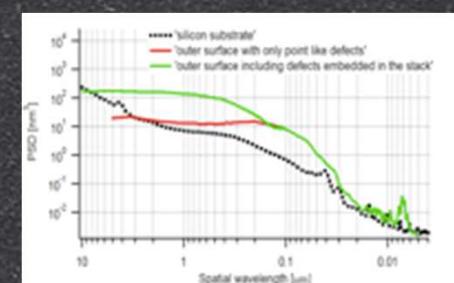
$$Q_{is} = [r_F(\theta_s) r_F(\theta_i)]^{1/2}$$

$Q_{is}$  : polarization factor

$r_F$  : Fresnel reflectivity



AFM

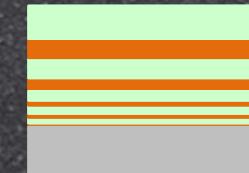
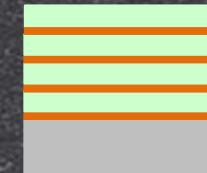


PSD (P)



# ➤ X-ray scattering formula for a multilayer

both periodic and graded

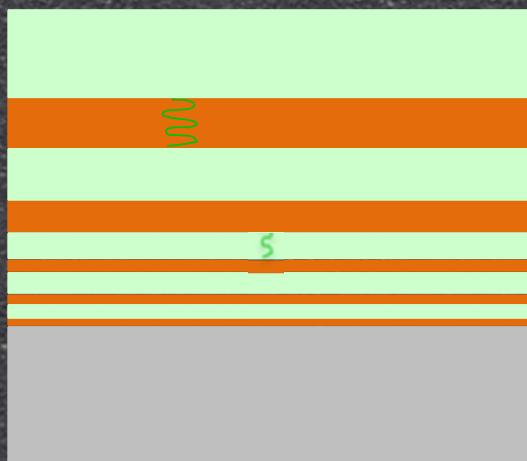


periodic

depth graded

$$\frac{1}{I_0} \frac{dI_s}{d\theta_s} = \frac{16\pi^2}{\lambda^3} Q_{is} \sin^2 \theta_s \sin \theta_i [P_{unc}(f) + P_{corr}(f)] =$$

$$= \frac{16\pi^2}{\lambda^3} Q_{is} \sin^2 \theta_s \sin \theta_i \left[ \sum_i T_i^2 P_i(f) + 2 \sum_{i>j} (-1)^{i+j} C_{ij}(f) T_i T_j \cos(\alpha \Delta_{ij}) \right]$$



electric fields

depth separation

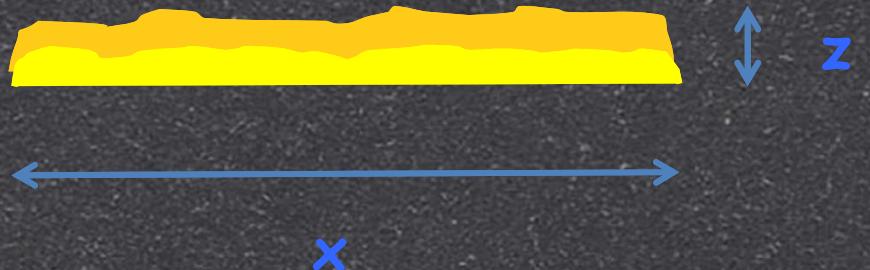
$$\alpha = 2\pi/\lambda (\sin \theta_s + \sin \theta_i)$$

# ➤ Roughness growth model (to compute internal PSD)

for a single layer

$$\frac{\partial z(x)}{\partial \tau} = -\nu |\nabla^n z(x)| + \frac{\partial \eta}{\partial \tau}$$

Stearns 1998



## SMOOTHING PROCESS

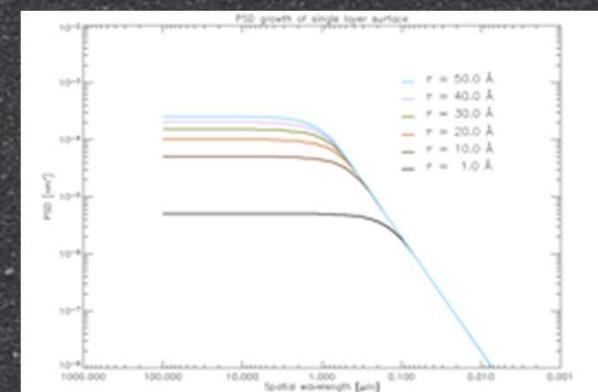
$\nu$  : linked to the growth spatial frequencies  
 $n$  : positive integer which depends on the smoothing process

## INCREASE IN ROUGHNESS

$\eta$  : random shot noise of the deposition process  
 $\tau$  : layer thickness

$$P^{\text{int}}(f) = \Omega \frac{1 - \exp(-2\nu|2\pi f|^n \tau)}{2\nu|2\pi f|^n}$$

$\Omega$  : volume of the deposited particles  
 $I^* = (\nu\tau)^{1/n}$



## ➤ Roughness growth model (to compute internal PSD) for a multilayer

$$P_i(f) = P_i^{\text{int}}(f) + P_i^{\text{ext}}(f) = P_i^{\text{int}}(f) + a_i(f)P_{i-1}(f)$$



Intrinsic PSD due to the deposition process

Replication on the underlying layer

replication factor  
 $a_i(f) = \exp(-\nu_i |2\pi f|^n \tau_i)$

... to calculate  $P_i$  and  $C_{ij}$  in the scattering formula

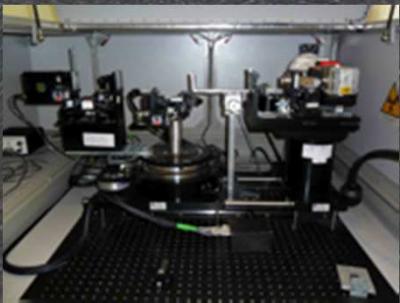
$$\frac{1}{I_0} \frac{dI_s}{d\theta_s} = \frac{16\pi^2}{\lambda^3} Q_{is} \sin^2 \theta_s \sin \theta_i \left[ \sum_i T_i P_i(f) + 2 \sum_{i>j} (-1)^{i+j} C_{ij}(f) T_i T_j \cos(\alpha \Delta_{ij}) \right]$$

# EXPERIMENTAL

# and SIMULATION

## XRR

X-rays  
diffractometer:  
BEDE scientific,  
mod. D1



## AFM

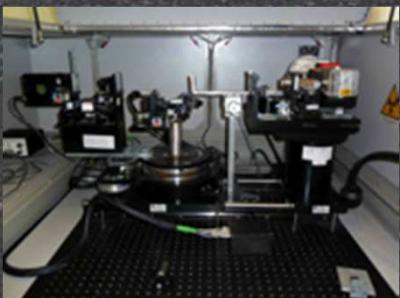
AFM: Bruker  
(formerly Veeco)  
mod. EXPLORER  
standalone

Measure substrate  
and outer layer



## XRS

X-rays  
diffractometer:  
BEDE scientific,  
mod. D1



## PPM

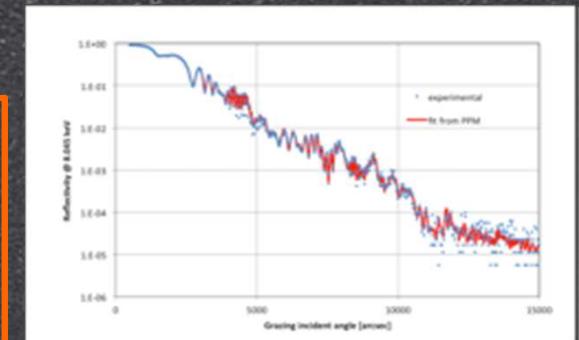
PPM (Pythonic Program for  
Multilayer), Mirone ESRF

### INPUT

- ◊ Nominal power law and densities

### OUTPUT

- ◊ Actual layers thicknesses and  
densities



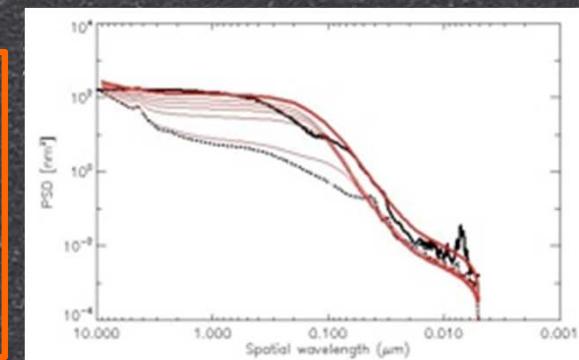
## Roughness growth

### INPUT

- ◊ PSD for substrate and outer layer
- ◊ Stack parameters from PPM
- ◊  $\Omega_i l_i n_i$  and  $\Omega_h l_h n_h$

### OUTPUT

- ◊  $P_i$ ,  $C_{ij}$



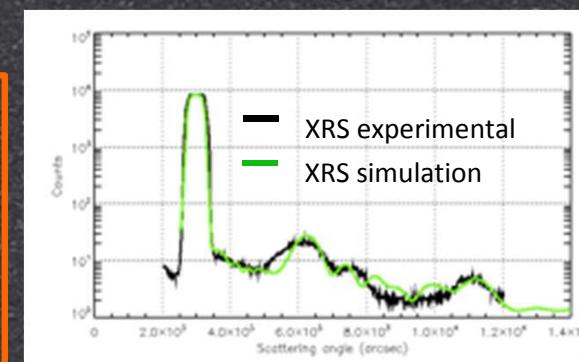
## XRS diagram

### INPUT

- ◊ Stack parameters from XRR/PPM
- ◊  $P_i$ ,  $C_{ij}$  from AFM/Stearns model

### OUTPUT

- ◊ XRS diagram



# Samples

Sample 1 Substrate : silicon

Periodic multilayer: N=40 bi-layers, W/Si,  $d=4.6\text{\AA}$ ,  $\Gamma=0.42$ ,  
deposited by e-beam evaporation

Sample 2 Substrate : silicon

Graded multilayer: N=100 bi-layers, Pt/C,  
deposited by magnetron sputtering

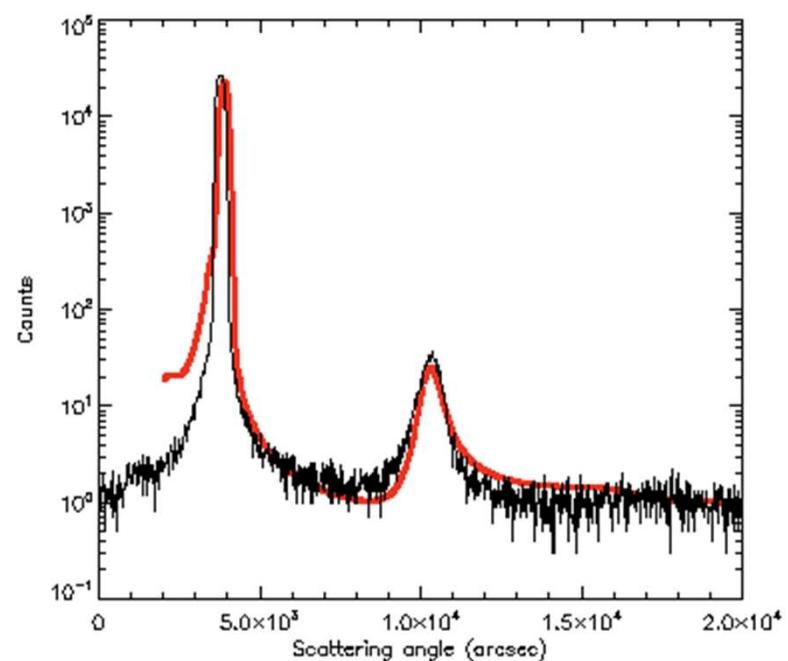


# Program upgrading validation

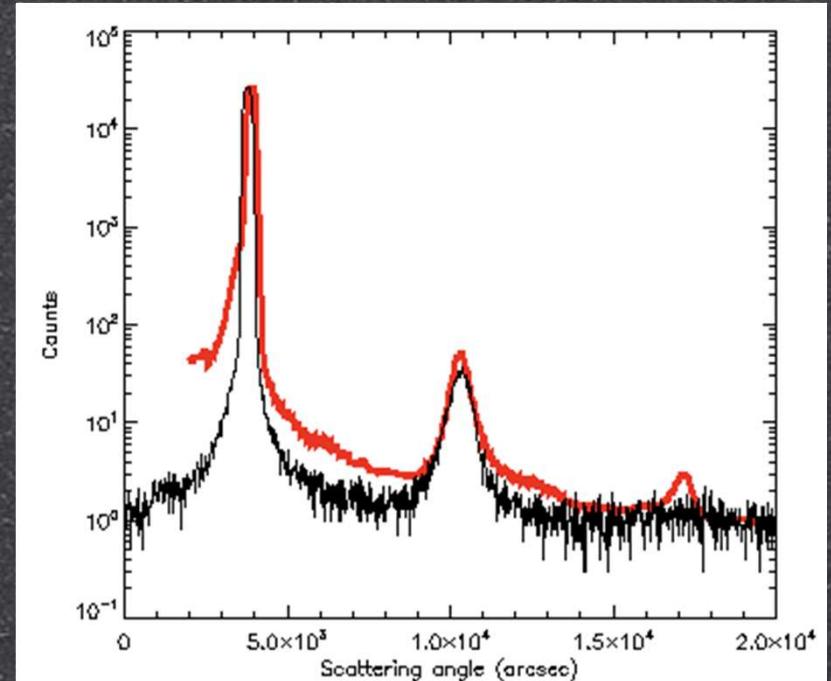
created for periodic multilayers (Canestrari, 2006), upgraded to graded multilayers (Salmaso, 2011/12)

## Sample 1: PERIODIC, W/Si

Incident energy = 8.045 keV (Cu K $\alpha$ , line)  
Incidence angle = first Bragg peak



With roughness growth



No roughness growth

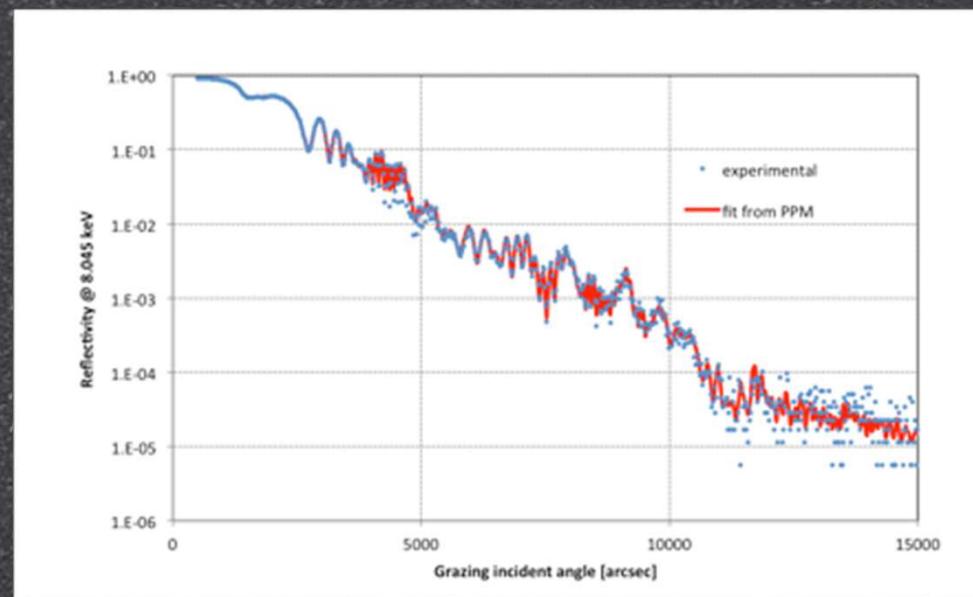


# Application to graded multilayers

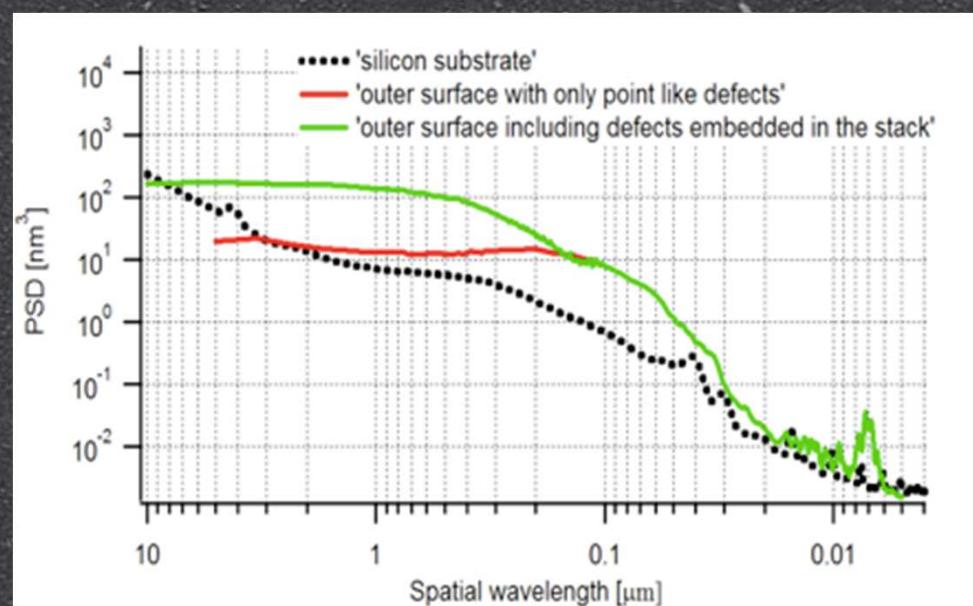
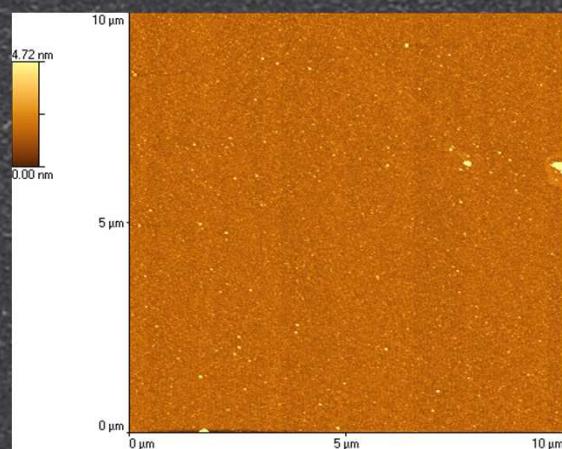
Sample 2, Pt/C

## ➤ XRR measurements

Incident energy = 8.045 keV (Cu  $\text{K}\alpha_1$  line)

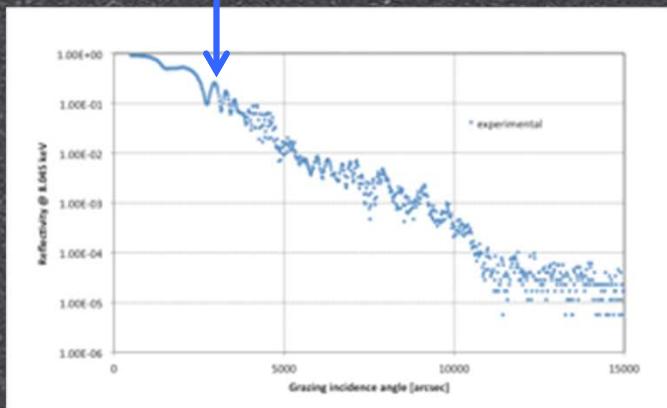


## ➤ AFM measurements

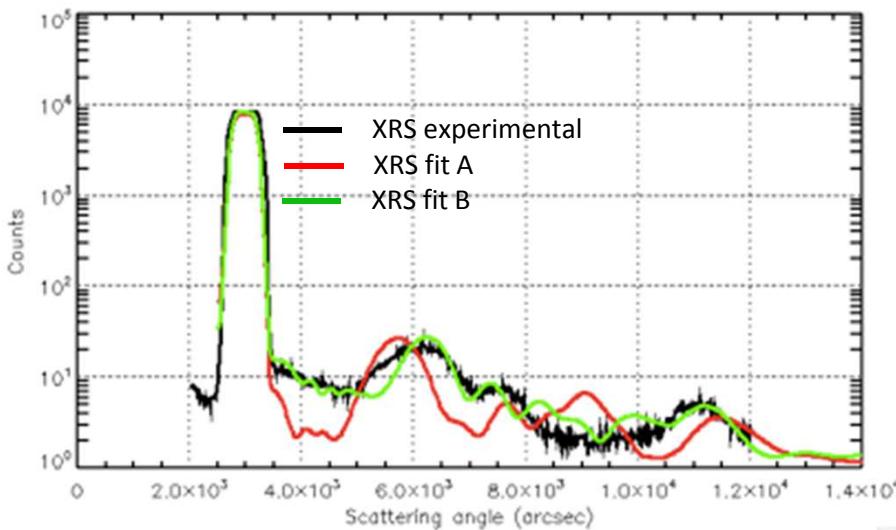


# Stack parameters optimization

$\theta_i = 3000 \text{ arcsec}$



## ➤ XRS measurements 1



Fit A : stack parameters from PPM

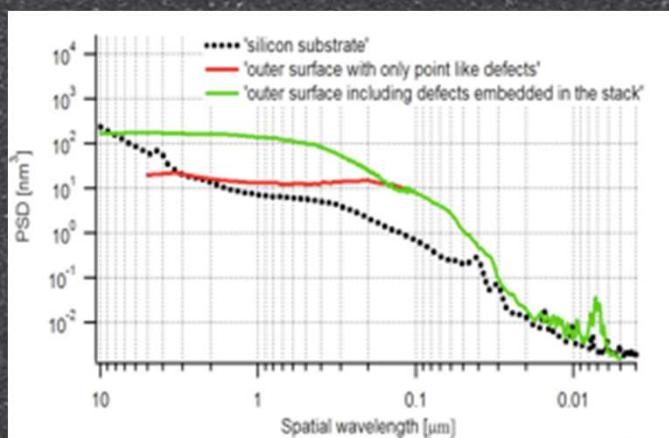
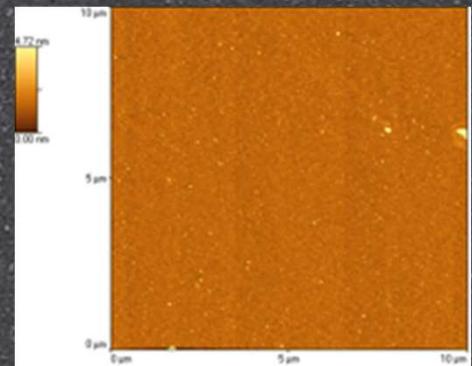
Fit B : optimized stack parameters

|       | Pt: $a$ [\AA], $b$ , $c$ | C: $a$ [\AA], $b$ , $c$ |
|-------|--------------------------|-------------------------|
| Fit A | 31.08, -0.90, 0.30       | 53.16, -0.96, 0.19      |
| Fit B | 31.00, -0.94, 0.23       | 53.00, -0.88, 0.21      |

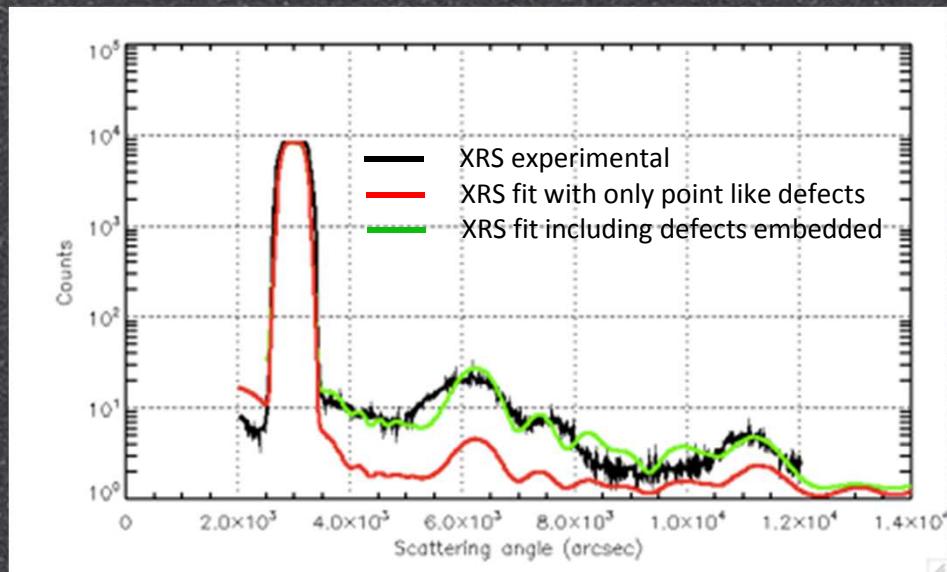
Layer thickness difference  $\leq 3\text{\AA}$  for all layers except first C layer where  $\Delta=15.3\text{\AA}$



# Defects contributing to XRS



## ➤ XRS measurements 1 $\theta_i=3000 \text{ arcsec}$

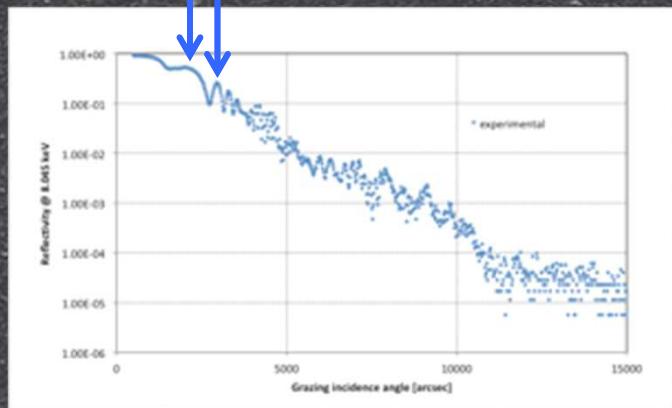


# Different incidence angles

## ➤ XRS measurements 3

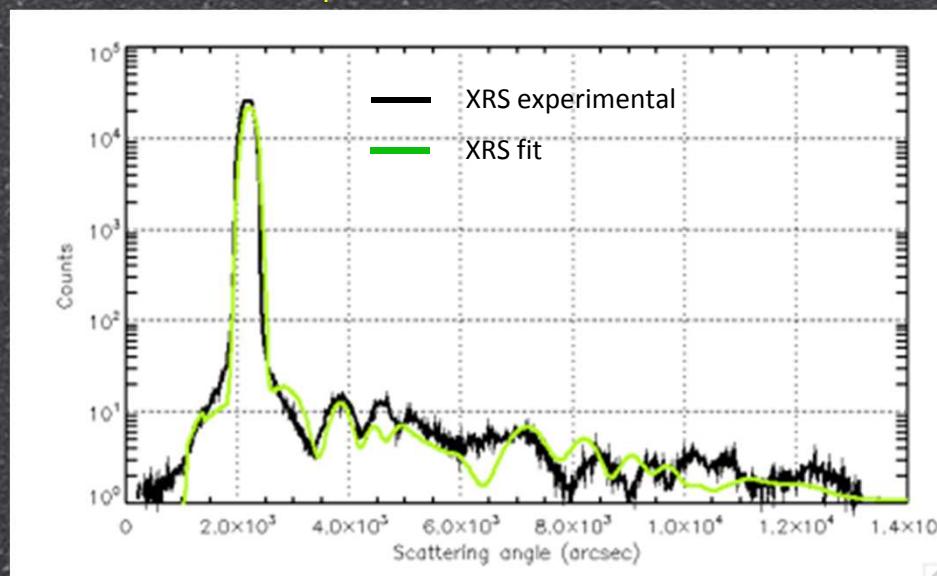
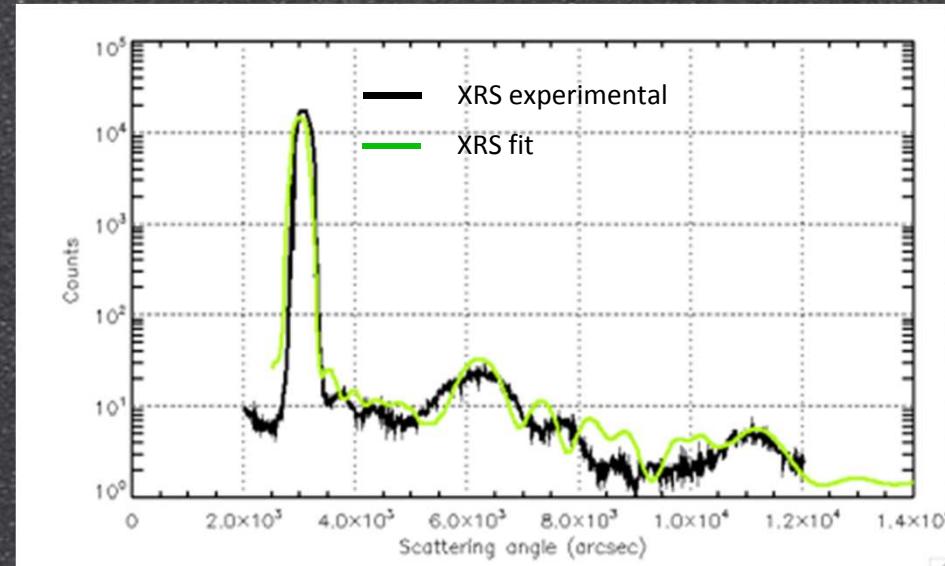
$\theta_i=2200$  arcsec

$\theta_i=3000$  arcsec



$\theta_i=2200$  arcsec

$\theta_i=3000$  arcsec



# Conclusions

- We have a protocol to predict XRS, and therefore imaging quality, from surface roughness for both periodic and graded multilayers
- The roughening model is validated by the fit of the XRS data
- XRS diagram is even more sensitive than XRR to the actual thickness trend in the stack
- We can separate surface defects by interfacial defects that contribute to XRS of the multilayer

## Further development

- Correction for internal refraction with variable  $\Gamma$
- Automatic search for best stack parameters

